

Abstract Submitted  
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**Evolution of Electronic Structure with Doping in  $(\text{La}_{2-x}\text{Sr}_x)\text{CuO}_4$**

X. J. ZHOU, Stanford University, T. YOSHIDA, University of Tokyo, W. L. YANG, V. BROUET, Stanford University, SEIKI KOMIYA, YOICHI ANDO, CRIEP, Tokyo, F. ZHOU, J. W. XIONG, W. X. TI, Z. X. ZHAO, IOP, China, T. SASAGAWA, T. KAKISHITA, H. EISAKI, S. UCHIDA, A. FUJIMORI, University of Tokyo, Z. HUSSAIN, Lawrence Berkeley National Lab, Z.-X. SHEN, Stanford University — High resolution angle-resolved photoemission measurements have been carried out on  $(\text{La}_{2-x}\text{Sr}_x)\text{CuO}_4$  (LSCO) over the entire doping range ( $x=0\sim 0.3$ ). Systematic evolution of the energy band, Fermi surface, and many-body effect with doping will be discussed.

X. J. Zhou  
Stanford University

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